

2SD2358

Silicon NPN epitaxial planar type

For low-frequency output amplification Complementary to 2SB1538

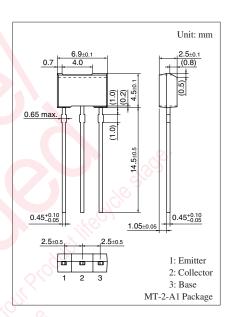
■ Features

- Low collector-emitter saturation voltage V_{CE(sat)}: < 0.15 V
- Allowing supply with the radial taping

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	10	V	
Collector-emitter voltage (Base open)	V_{CEO}	10	V	
Emitter-base voltage (Collector open)	V _{EBO}	5	V	
Collector current	I_{C}	1	A	
Peak collector current	I_{CP}	1.2	A	
Collector power dissipation *	P _C	1	W	
Junction temperature	T_{j}	150	°C	
Storage temperature	T _{stg}	-55 to +150	°CO	

Note) *: Printed circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion



■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = 10 \mu\text{A}, I_E = 0$	10	0.0		V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	10			V
Emitter-base voltage (Collector open)	V_{EBO}	$I_E = 10 \mu\text{A}, I_C = 0$	5			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 7 \text{ V}, I_{E} = 0$			1	μΑ
Forward current transfer ratio	h _{FE}	$V_{CE} = 2 \text{ V}, I_{C} = 100 \text{ mA}$	200		800	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 500 \text{ mA}, I_B = 20 \text{ mA}$			0.15	V
Transition frequency	f_T	$V_{CB} = 5 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		120		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 20 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		30		pF

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

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